

1 Characteristics

Table 2. Absolute ratings (limiting values, anode terminals 1 and 3 short circuited)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	60	V
$I_{F(RMS)}$	Forward rms current	45	A
$I_{F(AV)}$	Average forward current $\delta = 0.5$	$T_c = 100\text{ }^{\circ}\text{C}$	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ ms sinusoidal}$	A
$P_{ARM}^{(1)}$	Repetitive peak avalanche power	3500	W
V_{ARM}	Maximum repetitive peak avalanche voltage	$t_p < 1\text{ }\mu\text{s}, T_j < 150\text{ }^{\circ}\text{C}$ $I_{AR} < 13\text{ A}$	V
T_{stg}	Storage temperature range	-65 to +175	$^{\circ}\text{C}$
T_j	Maximum operating junction temperature ⁽²⁾	150	$^{\circ}\text{C}$

1. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the STMicroelectronics' application notes AN1768 and AN2025.
2. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	2.0	$^{\circ}\text{C/W}$

Table 4. Static electrical characteristics (anode terminals short circuited)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ }^{\circ}\text{C}$	$V_R = V_{RRM}$	-	-	90	μA
		$T_j = 125\text{ }^{\circ}\text{C}$		-	20	50	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ }^{\circ}\text{C}$	$I_F = 15\text{ A}$	-	-	0.59	V
		$T_j = 125\text{ }^{\circ}\text{C}$		-	0.46	0.52	
		$T_j = 25\text{ }^{\circ}\text{C}$	$I_F = 30\text{ A}$	-	-	0.72	
		$T_j = 125\text{ }^{\circ}\text{C}$		-	0.57	0.67	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$
2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.55 \times I_{F(AV)} + 0.004 \times I_{F(RMS)}^2$$

Figure 1. Average forward power dissipation versus average forward current

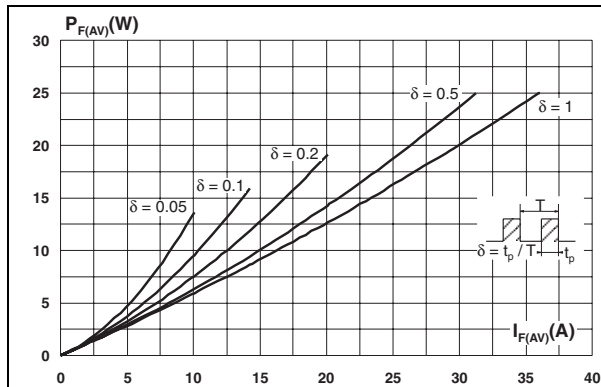
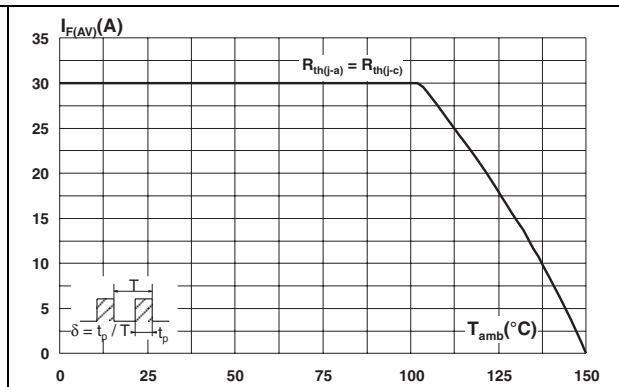
Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$)

Figure 3. Normalized avalanche power derating versus pulse duration

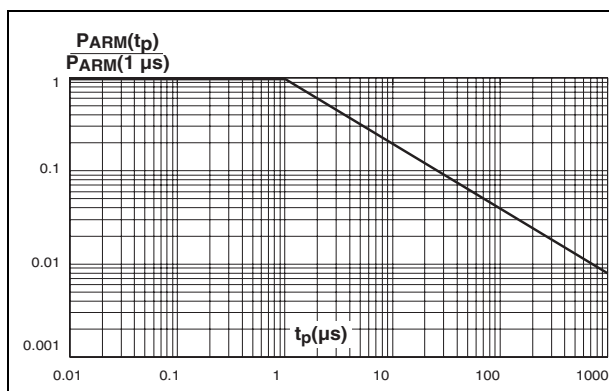


Figure 4. Normalized avalanche power derating versus junction temperature

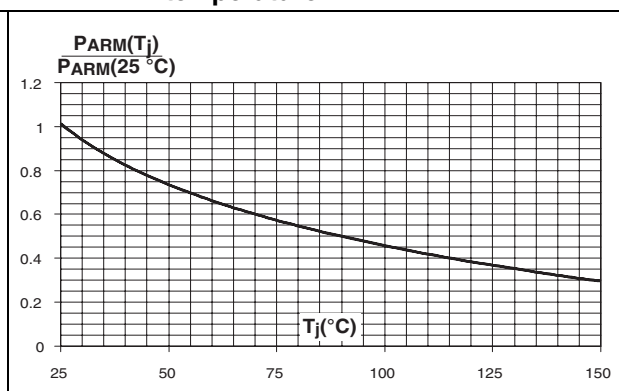


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values)

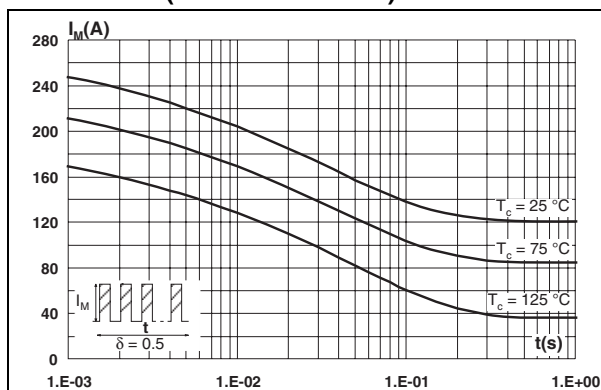


Figure 6. Relative variation of thermal impedance junction to case versus pulse duration

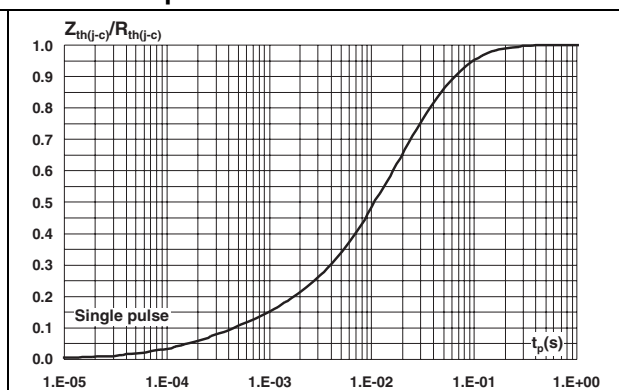


Figure 7. Reverse leakage current versus reverse voltage applied (typical values)

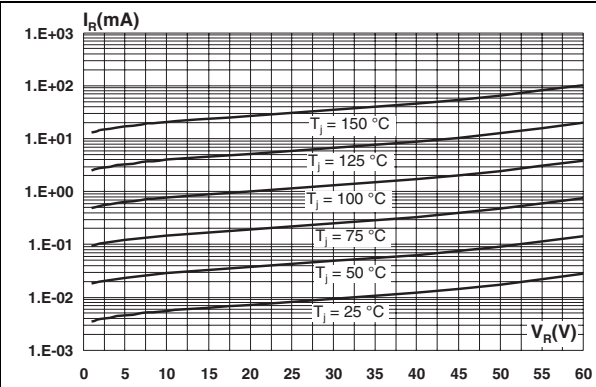


Figure 8. Junction capacitance versus reverse voltage applied (typical values)

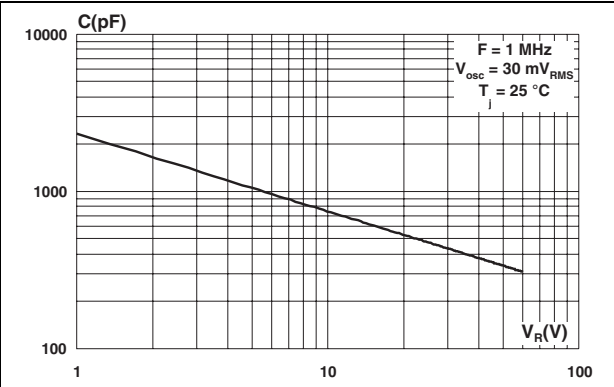


Figure 9. Forward voltage drop versus forward current

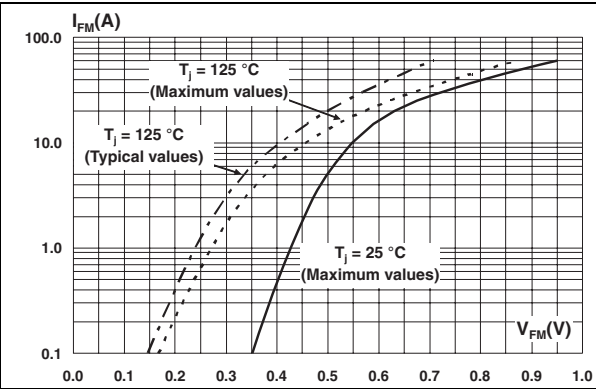


Figure 10. Thermal resistance junction to ambient versus copper surface under tab

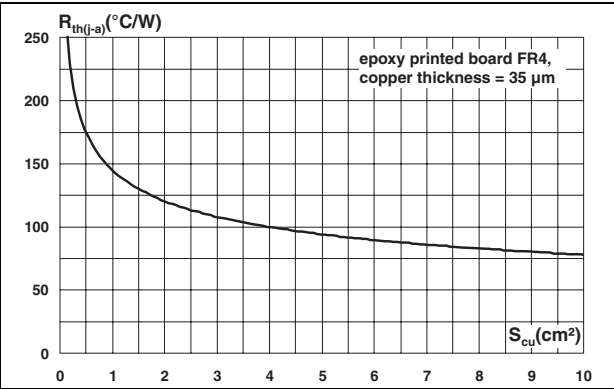
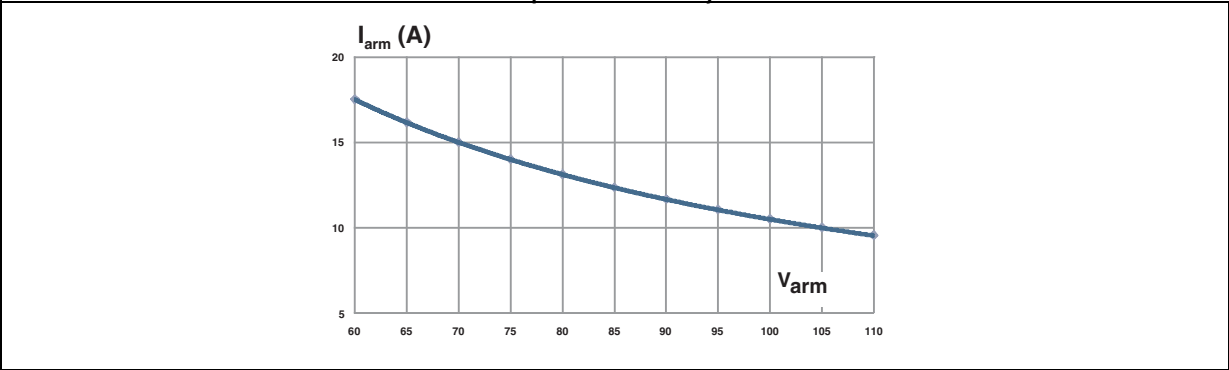


Figure 11. Reverse safe operating area ($t_p < 1 \mu s$ and $T_J < 150^\circ\text{C}$)



2 Package information

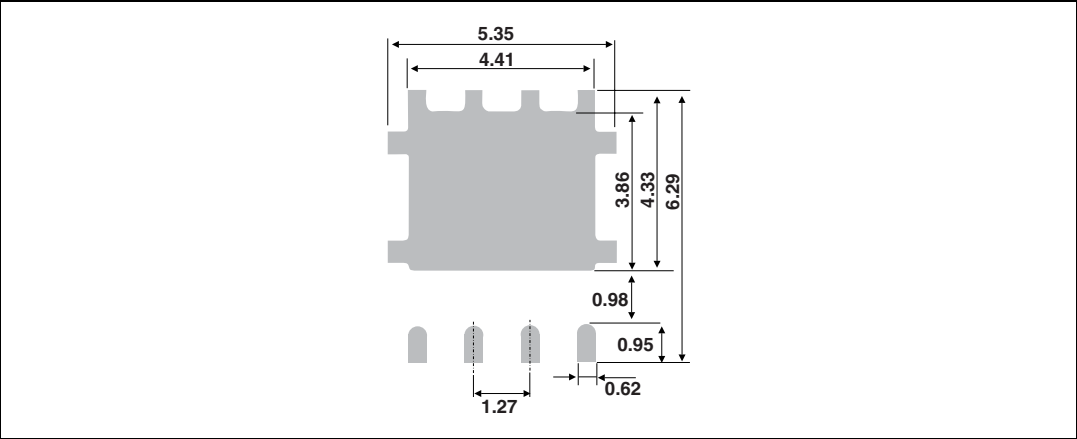
- Epoxy meets UL94,V0
- Lead-free package

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 5. PowerFLAT 5x6 dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.80		1.00	0.031		0.039
A1	0.02		0.05	0.001		0.002
A2		0.25			0.010	
b	0.30		0.50	0.012		0.020
D		5.20			0.205	
D2	4.11		4.31	0.162		0.170
e		1.27			0.050	
E		6.15			0.242	
E2	3.50		3.70	0.138		0.146
L	0.50		0.80	0.020		0.031
K	1.275		1.575	0.050		0.062

Figure 12. Footprint (dimensions in mm)



[illegible]

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS30M60DJF-TR	PS30 M60	PowerFLAT 5x6	95 mg	3000	Tape and reel

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
18-Apr-2012	1	First issue.

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